Diode Semiconductor Device - Page 1 of 1



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Inclosure Materia	21.
Glass	
Overall Length:	
	ches and 0.200 inches
Terminal Length	
Between 1.000 in	ches and 1.500 inches
Overall Diameter	:
Between 0.055 in	ches and 0.090 inches
Joint Electronic	Device Engineering Council/jedec/case Outline Designation:
Do-35	
Mounting Metho	d:
Terminal	
Semiconductor I	Material:
Silicon	
Voltage Rating Ir	Nolts Per Characteristic:
25.0 regulator vo	ltage
Voltage Tolerand	e In Percent:
-5.0/+5.0	
Current Rating P	er Characteristic:
15.00 milliampere	s repetitive peak forward current
Power Rating Pe	r Characteristic:
500.0 milliwatts sr	nall-signal input power, common-collector preset
Maximum Opera	ting Tempurature Per Measurement Point:
200.0 degrees cel	sius ambient air
Test Data Docum	nent:
81349-mil-s-1950	0 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificati
format; excludes	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	d performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type A	nd Quantity:
2 uninsulated wire	elead
Specification Da	ta:
81349-mil-s-1950	0/437 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	